

LaPtSi Structure: ABC_tI12_109_a_a_a-001

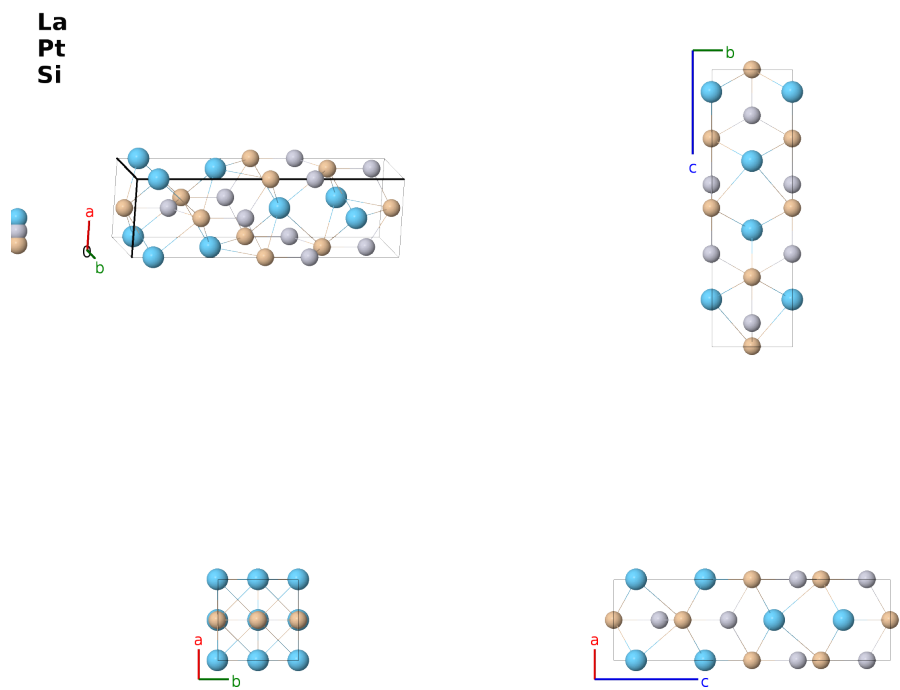
This structure previously used the label(s) **ABC_tI12_109_a_a_a**. Calls to these addresses will be redirected here.

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<https://aflow.org/prototype-encyclopedia/RTEY>

https://aflow.org/prototype-encyclopedia/ABC_tI12_109_a_a_a-001



Prototype	LaPtSi
AFLOW prototype label	ABC_tI12_109_a_a_a-001
ICSD	27224
CCDC	1602535
Pearson symbol	tI12
Space group number	109
Space group symbol	$I4_1md$
AFLOW prototype command	<code>aflow --proto=ABC_tI12_109_a_a_a-001 --params=a, c/a, z₁, z₂, z₃</code>

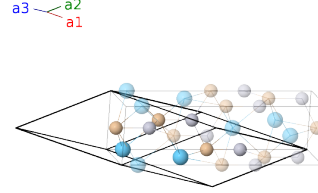
Other compounds with this structure

EuPtAs, CeAlSi, CeIrP, CeNiSi, CePtSi, GdGaSi, LaAlGe, LaAlSi, LaIrP, LaNiSi, LaPrP, LaPtGe, LaRhAs, NdAlSi, NdIrP, NdNiSi, NdPtSi, PrAlGe, PrAlSi, PrIrP, PrPtSi, PtSmSi, SmAlSi

- The sample examined by (Klepp, 1982) has 2% silicon on the platinum site and 2% platinum on the silicon site.
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Body-centered Tetragonal primitive vectors

$$\begin{aligned}\mathbf{a}_1 &= -\frac{1}{2}a\hat{\mathbf{x}} + \frac{1}{2}a\hat{\mathbf{y}} + \frac{1}{2}c\hat{\mathbf{z}} \\ \mathbf{a}_2 &= \frac{1}{2}a\hat{\mathbf{x}} - \frac{1}{2}a\hat{\mathbf{y}} + \frac{1}{2}c\hat{\mathbf{z}} \\ \mathbf{a}_3 &= \frac{1}{2}a\hat{\mathbf{x}} + \frac{1}{2}a\hat{\mathbf{y}} - \frac{1}{2}c\hat{\mathbf{z}}\end{aligned}$$



Basis vectors

	Lattice coordinates		Cartesian coordinates	Wyckoff position	Atom type
$\mathbf{B}_1$	$= z_1 \mathbf{a}_1 + z_1 \mathbf{a}_2$	$=$	$cz_1 \hat{\mathbf{z}}$	(4a)	La I
$\mathbf{B}_2$	$= (z_1 + \frac{3}{4}) \mathbf{a}_1 + (z_1 + \frac{1}{4}) \mathbf{a}_2 + \frac{1}{2} \mathbf{a}_3$	$=$	$\frac{1}{2}a\hat{\mathbf{y}} + c(z_1 + \frac{1}{4})\hat{\mathbf{z}}$	(4a)	La I
$\mathbf{B}_3$	$= z_2 \mathbf{a}_1 + z_2 \mathbf{a}_2$	$=$	$cz_2 \hat{\mathbf{z}}$	(4a)	Pt I
$\mathbf{B}_4$	$= (z_2 + \frac{3}{4}) \mathbf{a}_1 + (z_2 + \frac{1}{4}) \mathbf{a}_2 + \frac{1}{2} \mathbf{a}_3$	$=$	$\frac{1}{2}a\hat{\mathbf{y}} + c(z_2 + \frac{1}{4})\hat{\mathbf{z}}$	(4a)	Pt I
$\mathbf{B}_5$	$= z_3 \mathbf{a}_1 + z_3 \mathbf{a}_2$	$=$	$cz_3 \hat{\mathbf{z}}$	(4a)	Si I
$\mathbf{B}_6$	$= (z_3 + \frac{3}{4}) \mathbf{a}_1 + (z_3 + \frac{1}{4}) \mathbf{a}_2 + \frac{1}{2} \mathbf{a}_3$	$=$	$\frac{1}{2}a\hat{\mathbf{y}} + c(z_3 + \frac{1}{4})\hat{\mathbf{z}}$	(4a)	Si I

References

- [1] K. Klepp and E. Parthé, *RPtSi phases ($R = \text{La, Ce, Pr, Nd, Sm and Gd}$) with an ordered ThSi_2 derivative structure*, Acta Crystallogr. Sect. B **38**, 1105–1108 (1982), doi:10.1107/S056774088200507X.

Found in

- [1] P. Villars and K. Cenzual, *Pearson's Crystal Data – Crystal Structure Database for Inorganic Compounds* (2013). ASM International.

First cited in

D. Hicks, M. J. Mehl, E. Gossett, C. Toher, O. Levy, R. M. Hanson, G. Hart, and S. Curtarolo, *The AFLOW Library of Crystallographic Prototypes: Part 2*, Comput. Mater. Sci. **161**, S1 (2019). doi: 10.1016/j.commatsci.2018.10.043